

preliminary

Schottky Diode

$$V_{RRM} = 15\text{ V}$$

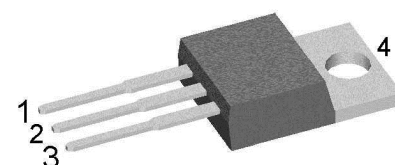
$$I_{FAV} = 2 \times 20\text{ A}$$

$$V_F = 0.39\text{ V}$$

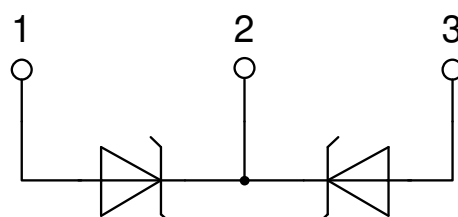
High Performance Schottky Diode
 Low Loss and Soft Recovery
 Common Cathode

Part number

DSB40C15PB



Backside: cathode



Features / Advantages:

- Very low V_f
- Extremely low switching losses
- Low I_{rm} values
- Improved thermal behaviour
- High reliability circuit operation
- Low voltage peaks for reduced protection circuits
- Low noise switching

Applications:

- Rectifiers in switch mode power supplies (SMPS)
- Free wheeling diode in low voltage converters

Package: TO-220

- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0

Disclaimer Notice

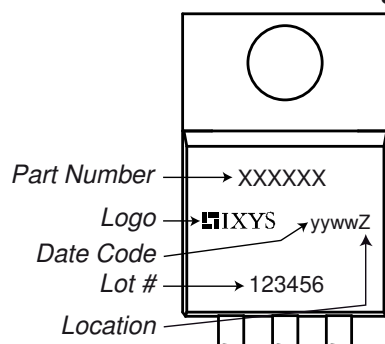
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Schottky				Ratings			
Symbol	Definition	Conditions		min.	typ.	max.	Unit
V _{RSM}	max. non-repetitive reverse blocking voltage	T _{VJ} = 25°C				15	V
V _{RRM}	max. repetitive reverse blocking voltage	T _{VJ} = 25°C				15	V
I _R	reverse current, drain current	V _R = 15 V	T _{VJ} = 25°C			5	mA
		V _R = 15 V	T _{VJ} = 100°C			40	mA
V _F	forward voltage drop	I _F = 20 A	T _{VJ} = 25°C			0.48	V
		I _F = 40 A				0.60	V
		I _F = 20 A	T _{VJ} = 125°C			0.39	V
		I _F = 40 A				0.54	V
I _{FAV}	average forward current	T _C = 130°C rectangular d = 0.5	T _{VJ} = 150°C			20	A
V _{F0}	threshold voltage	} for power loss calculation only		T _{VJ} = 150°C		0.23	V
r _F	slope resistance					7.2	mΩ
R _{thJC}	thermal resistance junction to case					1.75	K/W
R _{thCH}	thermal resistance case to heatsink				0.5		K/W
P _{tot}	total power dissipation	T _C = 25°C				70	W
I _{FSM}	max. forward surge current	t = 10 ms; (50 Hz), sine; V _R = 0 V		T _{VJ} = 45°C		390	A
C _J	junction capacitance	V _R = 3 V f = 1 MHz		T _{VJ} = 25°C		1.28	nF

preliminary

Package TO-220			Ratings			
Symbol	Definition	Conditions	min.	typ.	max.	Unit
I_{RMS}	RMS current	per terminal ¹⁾			35	A
T_{VJ}	virtual junction temperature		-55		150	°C
T_{op}	operation temperature		-55		125	°C
T_{stg}	storage temperature		-55		150	°C
Weight				2		g
M_D	mounting torque		0.4		0.6	Nm
F_C	mounting force with clip		20		60	N

Product Marking



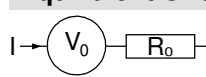
Part description

D = Diode
 S = Schottky Diode
 B = ultra low VF
 40 = Current Rating [A]
 C = Common Cathode
 15 = Reverse Voltage [V]
 PB = TO-220AB (3)

Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	DSB40C15PB	DSB40C15PB	Tube	50	502802

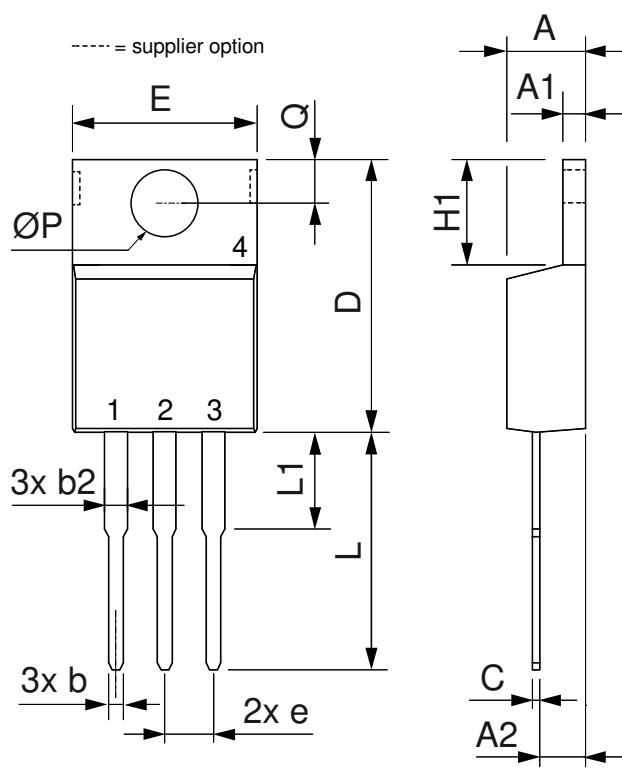
Equivalent Circuits for Simulation

* on die level

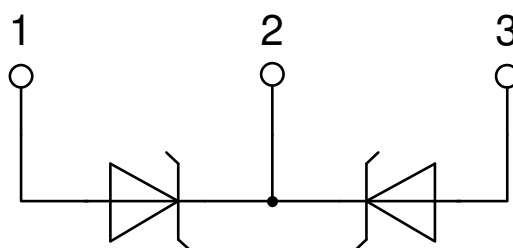
 $T_{VJ} = 150^{\circ}\text{C}$


Schottky

$V_{0\max}$	threshold voltage	0.23	V
$R_{0\max}$	slope resistance *	4.1	mΩ

Outlines TO-220


Dim.	Millimeter		Inches	
	Min.	Max.	Min.	Max.
A	4.32	4.82	0.170	0.190
A1	1.14	1.39	0.045	0.055
A2	2.29	2.79	0.090	0.110
b	0.64	1.01	0.025	0.040
b2	1.15	1.65	0.045	0.065
C	0.35	0.56	0.014	0.022
D	14.73	16.00	0.580	0.630
E	9.91	10.66	0.390	0.420
e	2.54	BSC	0.100	BSC
H1	5.85	6.85	0.230	0.270
L	12.70	13.97	0.500	0.550
L1	2.79	5.84	0.110	0.230
ØP	3.54	4.08	0.139	0.161
Q	2.54	3.18	0.100	0.125



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